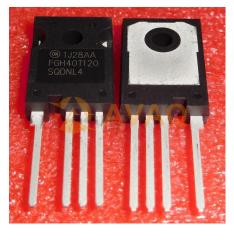


IGBT, Ultra Field Stop

Manufacturer:	ON Semiconductor, LLC
Package/Case:	TO-247
Product Type:	Thyristors
RoHS:	RoHS Compliant/Lead free W
Lifecycle:	Active



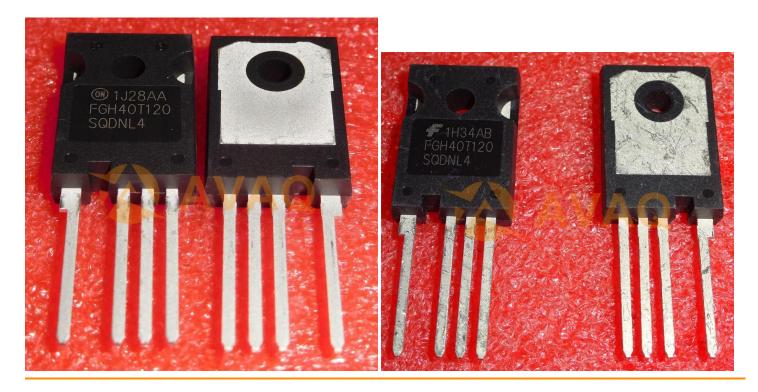


General Description

This Insulated Gate Bipolar Transistor (IGBT) features a robust andcost effective Ultra Field Stop Trench construction, and provides superior performance in demanding switching applications, offeringboth low on?state voltage and minimal switching loss. The IGBT is used for UPS and solar applications. Incorporated into the device a soft and fast co?packaged free wheeling diode with a low forwardvoltage.

Key Features

Extremely Efficient Trench with Field Stop Technology? TJmax = 175°C? Soft Fast Reverse Recovery Diode? Optimized for High Speed Solar Switching? These are Pb?Free Devices inverterUPSWelding



AVAQ SEMICONDUCTOR CO., LIMITED

Application

Recommended For You

FGH40N60SFDTU ON Semiconductor, LLC TO-247

FGA40N65SMD ON Semiconductor, LLC TO-3P

FGH75T65SHDTL4 ON Semiconductor, LLC TO-247-4

FGY75T120SQDN ON Semiconductor, LLC TO-247

FGD3040G2-F085C ON Semiconductor, LLC TO-252 FGL60N100BNID ON Semiconductor, LLC TO-264

FGH75T65SQDNL4 ON Semiconductor, LLC TO247

FGH80N60FDTU ON Semiconductor, LLC TO-247

FGH40T65UPD ON Semiconductor, LLC TO-247

FGA40T65SHD ON Semiconductor, LLC TO-3P FGA60N65SMD ON Semiconductor, LLC TO-3P

FGH75T65UPD ON Semiconductor, LLC TO-247

ON Semiconductor, LLC TO-247

FGH40T100SMD

FGA30T65SHD ON Semiconductor, LLC TO-3P

FGA30N65SMD ON Semiconductor, LLC TO-3P